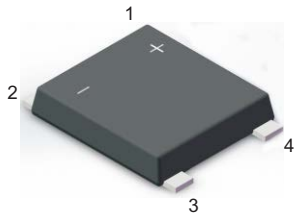
MB40B-MB40M

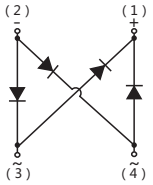
Features:

- ☐ Glass Passivated Chip Junction
- ☐ Reverse Voltage - 100 to 1000 V
- ☐ Forward Current - 4.0 A
- ☐ High Surge Current Capability
- ☐ Designed for Surface Mount Application

UMSB

RoHS COMPLIANT





PINNING

PIN	DESCRIPTION
1	Output Anode (+)
2	Output Cathode (-)
3	Input Pin (~)
4	Input Pin (~)

Absolute Maximum Ratings (Ta=25℃ unless otherwise noted)

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Parameter	Symbols	MB40B	MB40D	MB40G	MSB40	MB40K	MB40M	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	100	200	400	600	800	1000	V
Average Rectified Output Current	I_O	4.0						A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}	95						A
Maximum Forward Voltage at 4.0 A	V_F	1.1						V
Maximum DC Reverse Current at Rated DC Blocking Voltage @T_A=25 °C @T_A=125 °C	I_R	5 100						μA
Typical Junction Capacitance (Note1)	C_j	50						pF
Operating and Storage Temperature Range	T_j, T_{stg}	-55 ~ +150						°C

Note: 1. Measured at 1MHz and applied reverse voltage of 4 V D.C.
2. Mounted on glass epoxy PC board with 4×1.5"×1.5" (3.81×3.81 cm) copper pad.

Typical Characteristics

Fig.1 Average Rectified Output Current Derating Curve

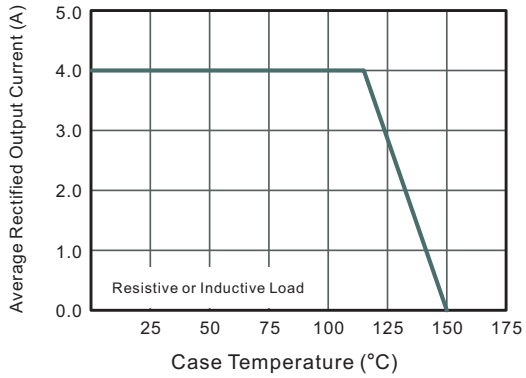


Fig.2 Typical Reverse Characteristics

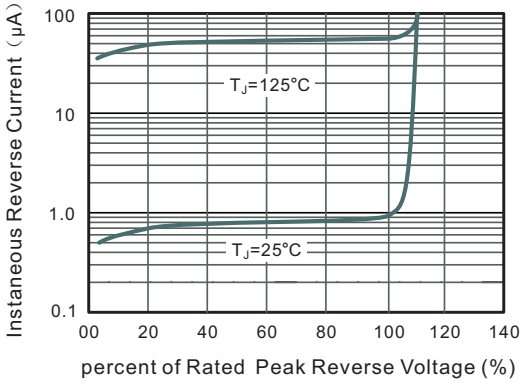


Fig.3 Typical Instaneous Forward Characteristics

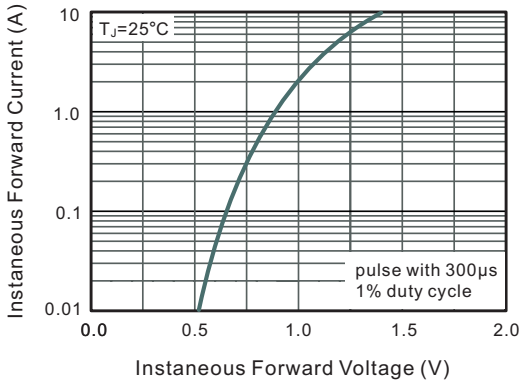


Fig.4 Typical Junction Capacitance

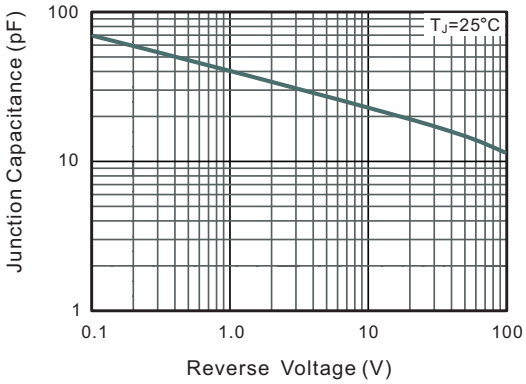
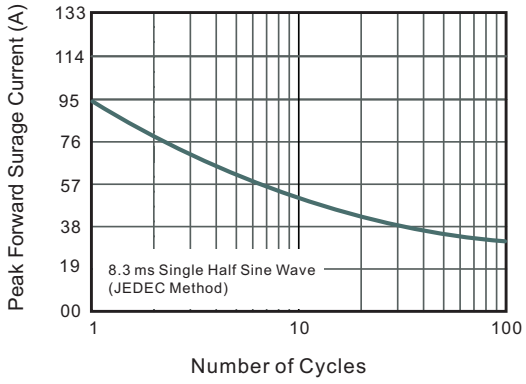


Fig.5 Maximum Non-Repetitive Peak Forward Surage Current



Package Dimension

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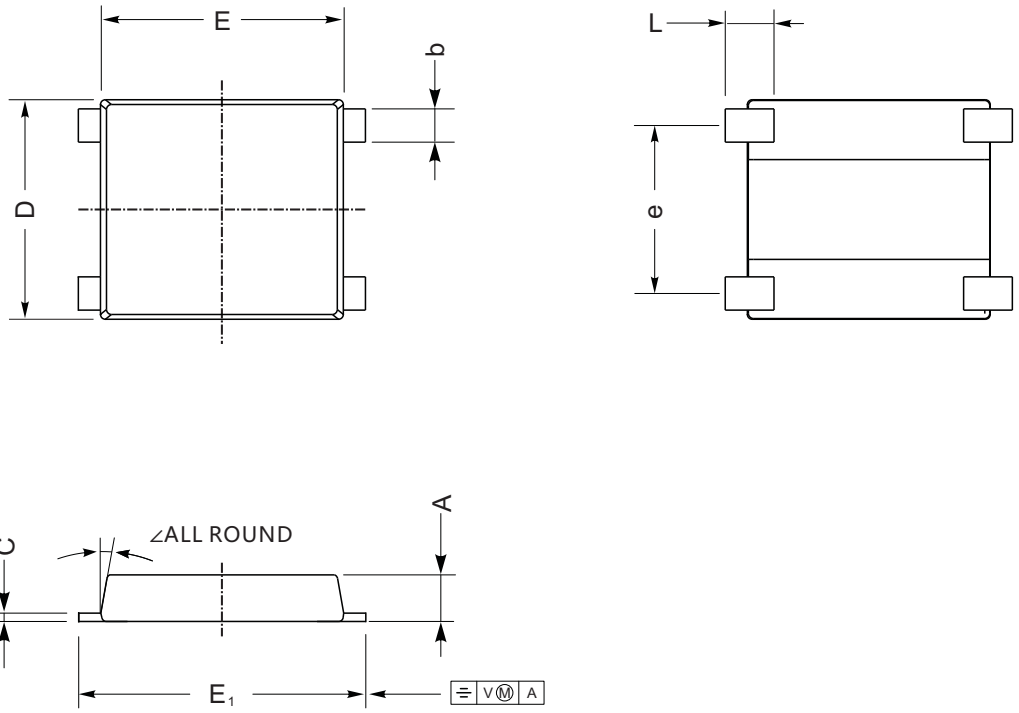

UMSB mechanical data

UNIT		A	C	D	E	E_1	L	e	b	∠
mm	max	1.5	0.29	7.0	7.6	8.9	1.6	5.3	1.15	10°
	min	1.3	0.17	6.2	7.1	8.4	1.0	4.9	0.95	
mil	max	59	12	276	299	350	55	209	45	
	min	51	7	244	280	331	31.5	193	37	